

DS26C31T/DS26C31M CMOS Quad TRI-STATE® Differential Line Driver

Check for Samples: [DS26C31M](#), [DS26C31T](#)

FEATURES

- TTL input compatible
- Typical propagation delays: 6 ns
- Typical output skew: 0.5 ns
- Outputs will not load line when $V_{CC} = 0V$
- DS26C31T meets the requirements of EIA standard RS-422
- Operation from single 5V supply
- TRI-STATE outputs for connection to system buses
- Low quiescent current
- Available in surface mount
- Mil-Std-883C compliant

DESCRIPTION

The DS26C31 is a quad differential line driver designed for digital data transmission over balanced lines. The DS26C31T meets all the requirements of EIA standard RS-422 while retaining the low power characteristics of CMOS. The DS26C31M is compatible with EIA standard RS-422; however, one exception in test methodology is taken ⁽¹⁾. This enables the construction of serial and terminal interfaces while maintaining minimal power consumption.

The DS26C31 accepts TTL or CMOS input levels and translates these to RS-422 output levels. This part uses special output circuitry that enables the drivers to power down without loading down the bus. This device has enable and disable circuitry common to all four drivers. The DS26C31 is pin compatible to the AM26LS31 and the DS26LS31.

All inputs are protected against damage due to electrostatic discharge by diodes to V_{CC} and ground.

Connection Diagram

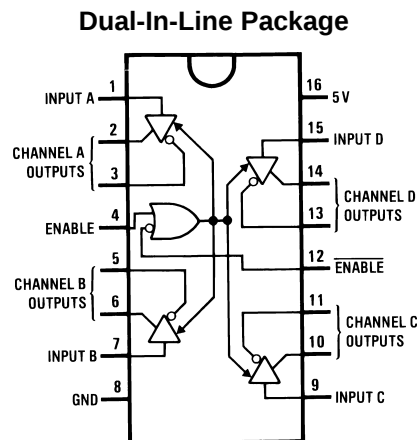


Figure 1. Top View
Order Number DS26C31TM or DS26C31TN
See NS Package Number M16A or N16E
For Complete Military Product Specifications,
refer to the appropriate SMD or MDS.
Order Number DS26C31ME/883, DS26C31MJ/883
or DS26C31MW/883
See NS Package Number E20A, J16A or W16A

(1) The DS26C31M (–55°C to +125°C) is tested with V_{OUT} between +6V and 0V while RS-422A condition is +6V and –0.25V.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

TRI-STATE is a registered trademark of Texas Instruments.

All other trademarks are the property of their respective owners.

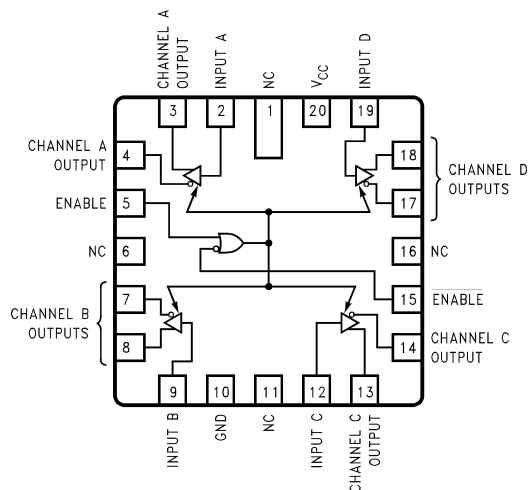


Figure 2. 20-Lead Ceramic Leadless Chip Carrier (E)

Truth Table⁽¹⁾

ENABLE	$\overline{\text{ENABLE}}$	Input	Non-Inverting Output	Inverting Output
L	H	X	Z	Z
All other combinations of enable inputs		L	L	H
		H	H	L

- (1) L = Low logic state
X = Irrelevant
H = High logic state
Z = TRI-STATE (high impedance)



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

Absolute Maximum Ratings ^{(1) (2)}

Supply Voltage (V_{CC})	–0.5V to 7.0V
DC Input Voltage (V_{IN})	–1.5V to $V_{CC} + 1.5V$
DC Output Voltage (V_{OUT})	–0.5V to 7V
Clamp Diode Current (I_{IK}, I_{OK})	±20 mA
DC Output Current, per pin (I_{OUT})	±150 mA
DC V_{CC} or GND Current, per pin (I_{CC})	±150 mA
Storage Temperature Range (T_{STG})	–65°C to +150°C
Max. Power Dissipation (P_D) @25°C ⁽³⁾	
Ceramic “J” Pkg.	2419 mW
Plastic “N” Pkg.	1736 mW
SOIC “M” Pkg.	1226 mW
Ceramic “W” Pkg.	1182 mW
Ceramic “E” Pkg.	2134 mW
Lead Temperature (T_L)	
(Soldering, 4 sec.)	260°C
This device does not meet 2000V ESD Rating. ⁽⁴⁾	

- (1) Unless otherwise specified, all voltages are referenced to ground. All currents into device pins are positive, all currents out of device pins are negative.
- (2) Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. They are not meant to imply that the device should be operated at these limits. The table of “Electrical Characteristics” provide conditions for actual device operation.
- (3) Ratings apply to ambient temperature at 25°C. Above this temperature derate N package at 13.89 mW/°C, J package 16.13 mW/°C, M package 9.80 mW/°C, E package 12.20 mW/°C, and W package 6.75 mW/°C.
- (4) ESD Rating: HBM (1.5 kΩ, 100 pF); Inputs ≥ 1500V; Outputs ≥ 1000V; EIAJ (0Ω, 200 pF) ≥ 350V

Operating Conditions

	Min	Max	Units
Supply Voltage (V_{CC})	4.50	5.50	V
DC Input or Output Voltage (V_{IN}, V_{OUT})	0	V_{CC}	V
Operating Temperature Range (T_A)			
DS26C31T	–40	+85	°C
DS26C31M	–55	+125	°C
Input Rise or Fall Times (t_r, t_f)		500	ns

DC Electrical Characteristics

$V_{CC} = 5V \pm 10\%$ (unless otherwise specified) ⁽¹⁾

Symbol	Parameter	Conditions		Min	Typ	Max	Units
V_{IH}	High Level Input Voltage			2.0			V
V_{IL}	Low Level Input Voltage					0.8	V
V_{OH}	High Level Output Voltage	$V_{IN} = V_{IH}$ or V_{IL} , $I_{OUT} = -20$ mA		2.5	3.4		V
V_{OL}	Low Level Output Voltage	$V_{IN} = V_{IH}$ or V_{IL} , $I_{OUT} = 20$ mA			0.3	0.5	V
V_T	Differential Output Voltage	$R_L = 100\Omega$ (2)		2.0	3.1		V
$ V_T - \bar{V}_T $	Difference In Differential Output	$R_L = 100\Omega$ (2)				0.4	V
V_{OS}	Common Mode Output Voltage	$R_L = 100\Omega$ (2)			1.8	3.0	V
$ V_{OS} - \bar{V}_{OS} $	Difference In Common Mode Output	$R_L = 100\Omega$ (2)				0.4	V
I_{IN}	Input Current	$V_{IN} = V_{CC}, GND, V_{IH},$ or V_{IL}				± 1.0	μA
I_{CC}	Quiescent Supply Current ⁽³⁾	DS26C31T $V_{IN} = V_{CC}$ or GND			200	500	μA
		$I_{OUT} = 0$ μA $V_{IN} = 2.4V$ or $0.5V$ (3)			0.8	2.0	mA
		DS26C31M $V_{IN} = V_{CC}$ or GND			200	500	μA
		$I_{OUT} = 0$ μA $V_{IN} = 2.4V$ or $0.5V$ (3)			0.8	2.1	mA
I_{OZ}	TRI-STATE Output Leakage Current	$V_{OUT} = V_{CC}$ or GND $\overline{ENABLE} = V_{IL}$ $\overline{ENABLE} = V_{IH}$			± 0.5	± 5.0	μA
I_{SC}	Output Short Circuit Current	$V_{IN} = V_{CC}$ or GND (2) (4)		-30		-150	mA
I_{OFF}	Output Leakage Current Power Off ⁽²⁾	DS26C31T $V_{CC} = 0V$ $V_{OUT} = 6V$ $V_{OUT} = -0.25V$				100	μA
		DS26C31M $V_{CC} = 0V$ $V_{OUT} = 6V$ $V_{OUT} = 0V$				-100	μA
						100	μA
						-100	μA
		(5)					

- (1) Unless otherwise specified, min/max limits apply across the recommended operating temperature range. All typicals are given for $V_{CC} = 5V$ and $T_A = 25^\circ C$.
- (2) See EIA Specification RS-422 for exact test conditions.
- (3) Measured per input. All other inputs at V_{CC} or GND.
- (4) This is the current sourced when a high output is shorted to ground. Only one output at a time should be shorted.
- (5) The DS26C31M ($-55^\circ C$ to $+125^\circ C$) is tested with V_{OUT} between +6V and 0V while RS-422A condition is +6V and -0.25V.

Switching Characteristics

 $V_{CC} = 5V \pm 10\%$, $t_r \leq 6 \text{ ns}$, $t_f \leq 6 \text{ ns}$ (Figure 3, Figure 4, Figure 5, Figure 6) ⁽¹⁾

Symbol	Parameter	Conditions	Min	Typ	Max		Units
					DS26C31T	CS26C31M	
t_{PLH}, t_{PHL}	Propagation Delays	S1 Open	2	6	11	14	ns
	Input to Output						
Skew	⁽²⁾	S1 Open		0.5	2.0	3.0	ns
t_{TLH}, t_{THL}	Differential Output Rise	S1 Open		6	10	14	ns
	And Fall Times						
t_{PZH}	Output Enable Time	S1 Closed		11	19	22	ns
t_{PZL}	Output Enable Time	S1 Closed		13	21	28	ns
t_{PHZ}	Output Disable Time	S1 Closed		5	9	12	ns
	⁽³⁾						
t_{PLZ}	Output Disable Time	S1 Closed		7	11	14	ns
	⁽³⁾						
C_{PD}	Power Dissipation			50			pF
	Capacitance ⁽⁴⁾						
C_{IN}	Input Capacitance			6			pF

- (1) Unless otherwise specified, min/max limits apply across the recommended operating temperature range. All typicals are given for $V_{CC} = 5V$ and $T_A = 25^\circ\text{C}$.
- (2) Skew is defined as the difference in propagation delays between complementary outputs at the 50% point.
- (3) Output disable time is the delay from $\overline{\text{ENABLE}}$ or $\overline{\text{ENABLE}}$ being switched to the output transistors turning off. The actual disable times are less than indicated due to the delay added by the RC time constant of the load.
- (4) C_{PD} determines the no load dynamic power consumption, $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$, and the no load dynamic current consumption, $I_S = C_{PD} V_{CC} f + I_{CC}$.

Comparison Table of Switching Characteristics into “LS-Type” Load

$V_{CC} = 5V$, $T_A = 25^\circ C$, $t_r \leq 6\text{ ns}$, $t_f \leq 6\text{ ns}$ (Figure 4, Figure 6, Figure 7, Figure 8) ⁽¹⁾

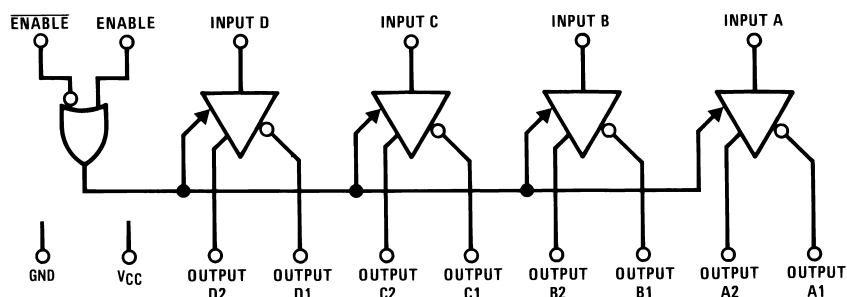
Symbol	Parameter	Conditions	DS26C31T		DS26LS31C		Units
			Typ	Max	Typ	Max	
t_{PLH} , t_{PHL}	Propagation Delays	$C_L = 30\text{ pF}$					
	Input to Output	S1 Closed	6	8	10	15	ns
		S2 Closed					
Skew	⁽²⁾	$C_L = 30\text{ pF}$					
		S1 Closed	0.5	1.0	2.0	6.0	ns
		S2 Closed					
t_{THL} , t_{TLH}	Differential Output Rise	$C_L = 30\text{ pF}$					
	and Fall Times	S1 Closed	4	6			ns
		S2 Closed					
t_{PLZ}	Output Disable Time	$C_L = 10\text{ pF}$					
	⁽³⁾	S1 Closed	6	9	15	35	ns
		S2 Open					
t_{PHZ}	Output Disable Time	$C_L = 10\text{ pF}$					
	⁽³⁾	S1 Open	4	7	15	25	ns
		S2 Closed					
t_{PZL}	Output Enable Time	$C_L = 30\text{ pF}$					
		S1 Closed	14	20	20	30	ns
		S2 Open					
t_{PZH}	Output Enable Time	$C_L = 30\text{ pF}$					
		S1 Open	11	17	20	30	ns
		S2 Closed					

(1) This table is provided for comparison purposes only. The values in this table for the DS26C31 reflect the performance of the device but are not tested or guaranteed.

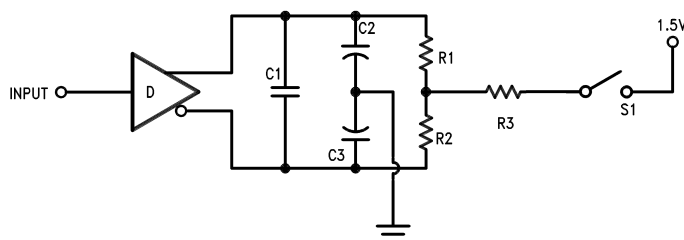
(2) Skew is defined as the difference in propagation delays between complementary outputs at the 50% point.

(3) Output disable time is the delay from $\overline{\text{ENABLE}}$ or $\overline{\text{ENABLE}}$ being switched to the output transistors turning off. The actual disable times are less than indicated due to the delay added by the RC time constant of the load.

Logic Diagram



AC Test Circuit and Switching Time Waveforms



Note: C1 = C2 = C3 = 40 pF (Including Probe and Jig Capacitance), R1 = R2 = 50Ω, R3 = 500Ω.

Figure 3. AC Test Circuit

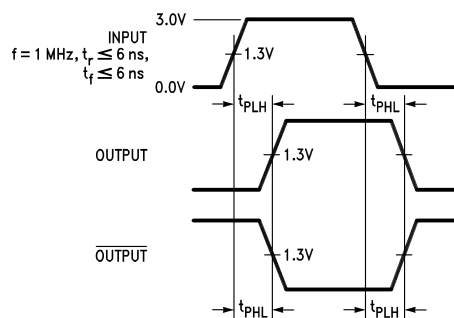


Figure 4. Propagation Delays

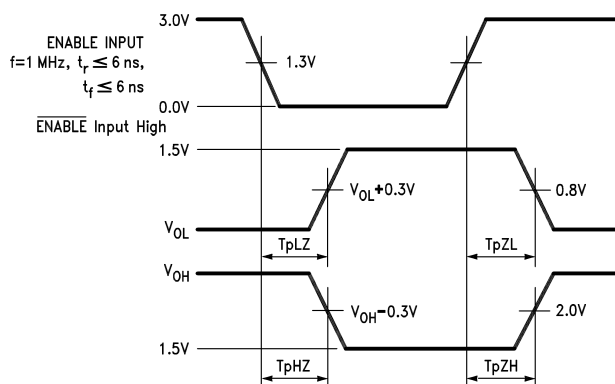
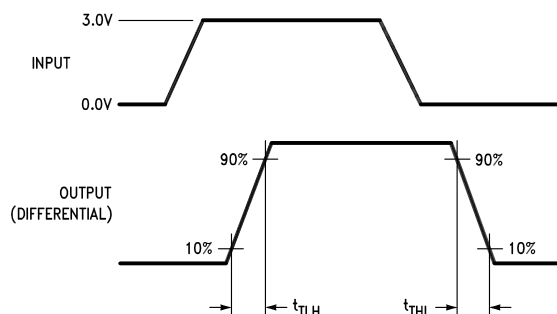


Figure 5. Enable and Disable Times



Input pulse; f = 1 MHz, 50%; $t_r \leq 6$ ns, $t_f \leq 6$ ns

Figure 6. Differential Rise and Fall Times

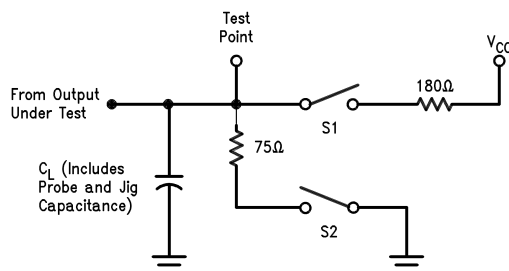


Figure 7. Load AC Test Circuit for "LS-Type" Load

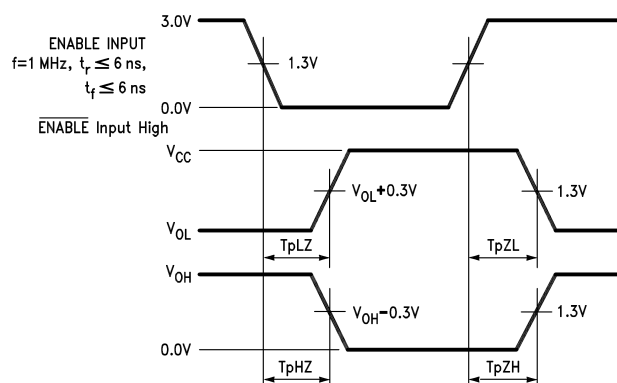
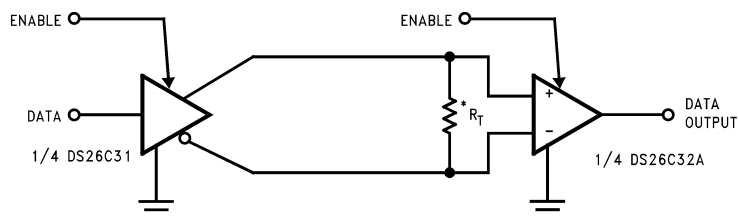


Figure 8. Enable and Disable Times for "LS-Type" Load

Typical Applications

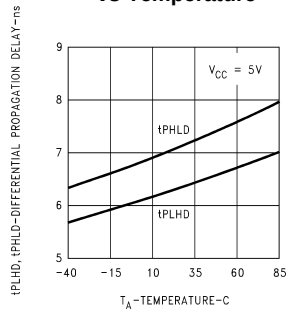


* R_T is optional although highly recommended to reduce reflection.

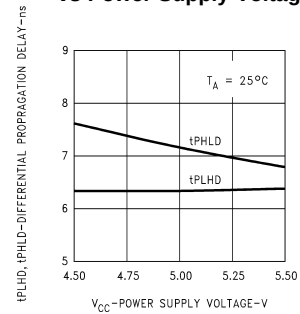
Figure 9. Two-Wire Balanced System, RS-422

Typical Performance Characteristics

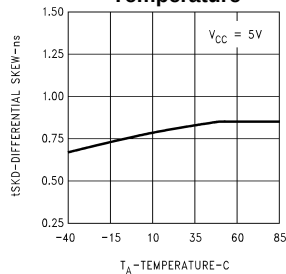
**Differential Propagation Delay
vs Temperature**



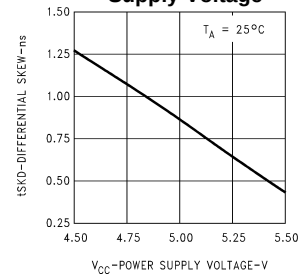
**Differential Propagation Delay
vs Power Supply Voltage**



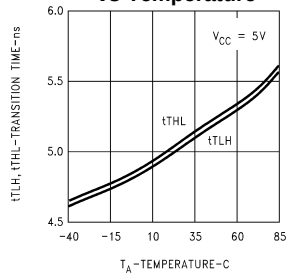
**Differential Skew vs
Temperature**



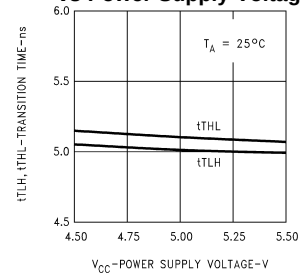
**Differential Skew
vs
Power
Supply Voltage**



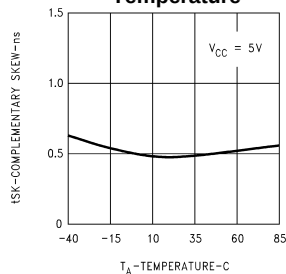
**Differential Transition Time
vs Temperature**



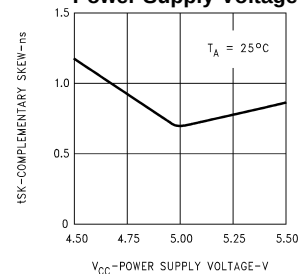
**Differential Transition Time
vs Power Supply Voltage**



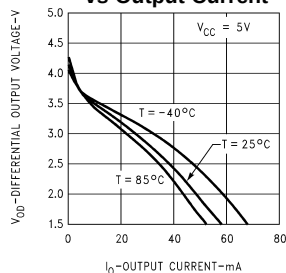
**Complementary Skew vs
Temperature**



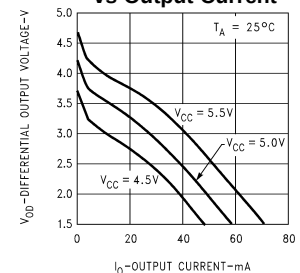
**Complementary Skew vs
Power Supply Voltage**



**Differential Output Voltage
vs Output Current**

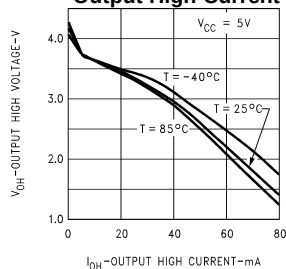


**Differential Output Voltage
vs Output Current**

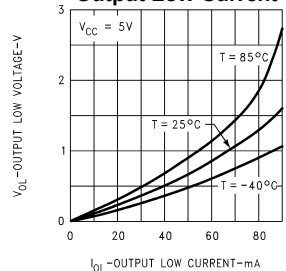


Typical Performance Characteristics (continued)

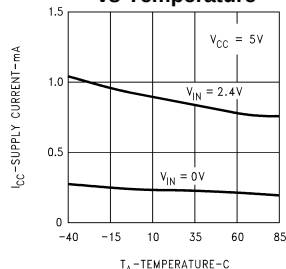
**Output High Voltage vs
Output High Current**



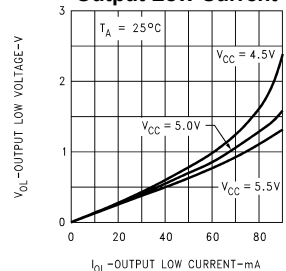
**Output Low Voltage vs
Output Low Current**



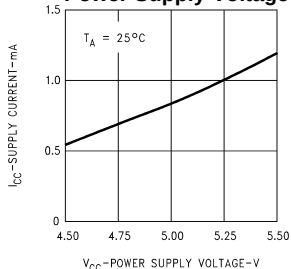
**Supply Current
vs Temperature**



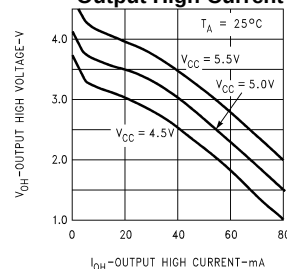
**Output Low Voltage vs
Output Low Current**



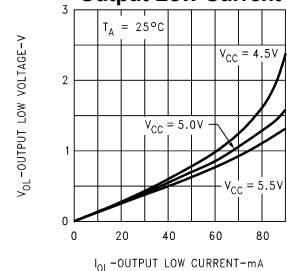
**Supply Current vs
Power Supply Voltage**



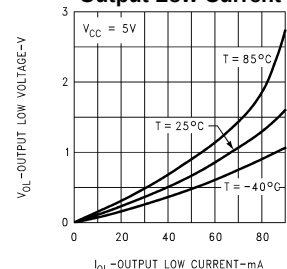
**Output High Voltage vs
Output High Current**



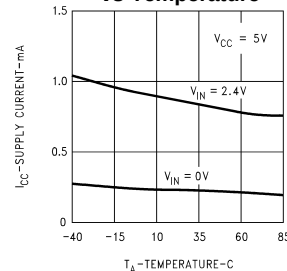
**Output Low Voltage vs
Output Low Current**



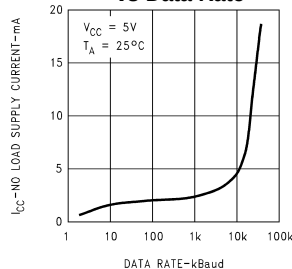
**Output Low Voltage vs
Output Low Current**



**Supply Current
vs Temperature**

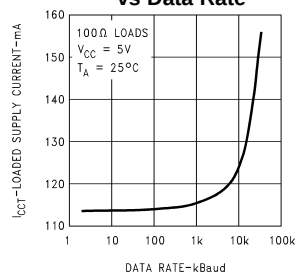


**No Load Supply Current
vs Data Rate**

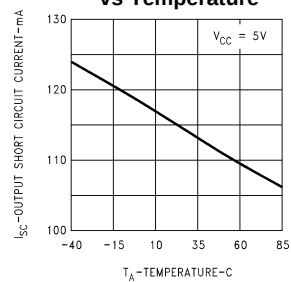


Typical Performance Characteristics (continued)

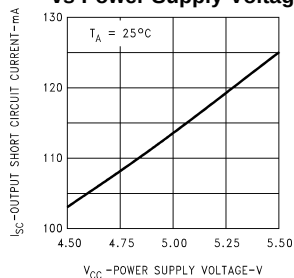
**Loaded Supply Current
vs Data Rate**



**Output Short Circuit Current
vs Temperature**



**Output Short Circuit Current
vs Power Supply Voltage**



PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)	Samples (Requires Login)
DS26C31TM	ACTIVE	SOIC	D	16	48	TBD	CU SNPB	Level-1-235C-UNLIM	
DS26C31TM/NOPB	ACTIVE	SOIC	D	16	48	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	
DS26C31TMX	ACTIVE	SOIC	D	16	2500	TBD	CU SNPB	Level-1-235C-UNLIM	
DS26C31TMX/NOPB	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	
DS26C31TN	ACTIVE	PDIP	NFG	16	25	TBD	Call TI	Level-1-NA-UNLIM	
DS26C31TN/NOPB	ACTIVE	PDIP	NFG	16	25	Green (RoHS & no Sb/Br)	CU SN	Level-1-NA-UNLIM	

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSELETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

TAPE AND REEL INFORMATION


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
DS26C31TMX	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.3	8.0	16.0	Q1
DS26C31TMX/NOPB	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.3	8.0	16.0	Q1

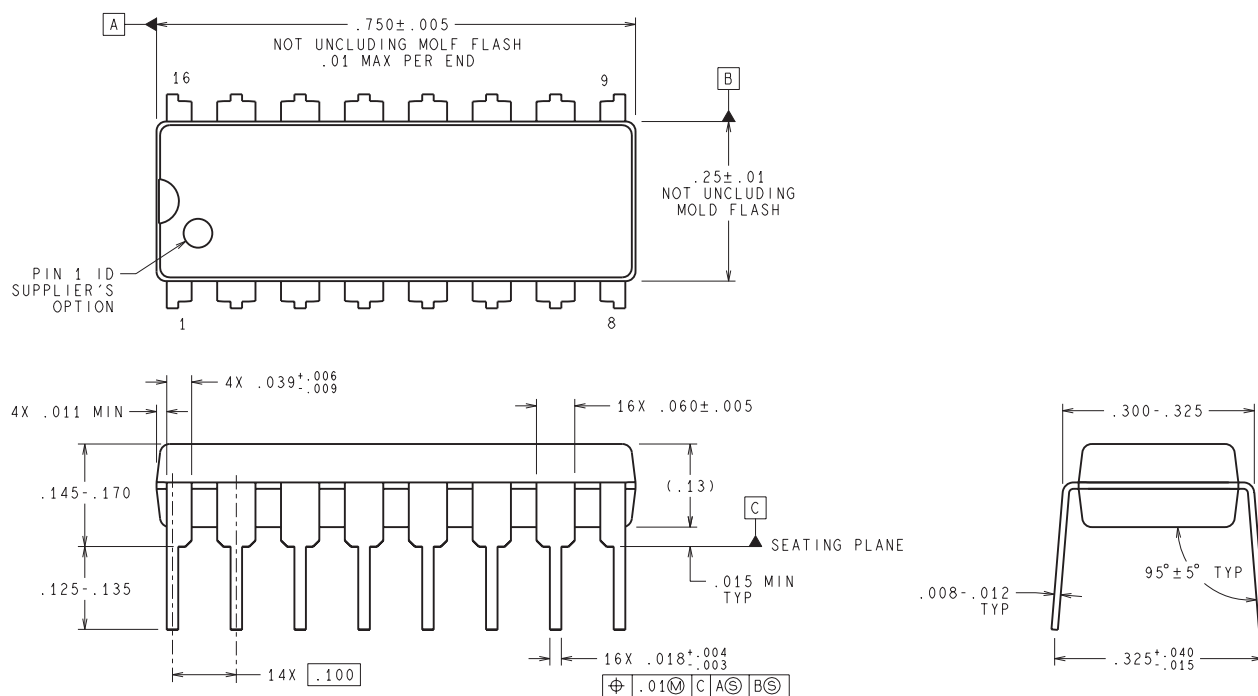
TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
DS26C31TMX	SOIC	D	16	2500	349.0	337.0	45.0
DS26C31TMX/NOPB	SOIC	D	16	2500	349.0	337.0	45.0

NFG0016E



DIMENSIONS ARE IN INCHES
DIMENSIONS IN () FOR REFERENCE ONLY

N16E (Rev G)

D (R-PDSO-G16)

PLASTIC SMALL OUTLINE



4040047-6/M 06/11

- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
 - D. Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
 - E. Reference JEDEC MS-012 variation AC.

IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, enhancements, improvements and other changes to its semiconductor products and services per JESD46, latest issue, and to discontinue any product or service per JESD48, latest issue. Buyers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All semiconductor products (also referred to herein as "components") are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its components to the specifications applicable at the time of sale, in accordance with the warranty in TI's terms and conditions of sale of semiconductor products. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by applicable law, testing of all parameters of each component is not necessarily performed.

TI assumes no liability for applications assistance or the design of Buyers' products. Buyers are responsible for their products and applications using TI components. To minimize the risks associated with Buyers' products and applications, Buyers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right relating to any combination, machine, or process in which TI components or services are used. Information published by TI regarding third-party products or services does not constitute a license to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of significant portions of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI components or services with statements different from or beyond the parameters stated by TI for that component or service voids all express and any implied warranties for the associated TI component or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Buyer acknowledges and agrees that it is solely responsible for compliance with all legal, regulatory and safety-related requirements concerning its products, and any use of TI components in its applications, notwithstanding any applications-related information or support that may be provided by TI. Buyer represents and agrees that it has all the necessary expertise to create and implement safeguards which anticipate dangerous consequences of failures, monitor failures and their consequences, lessen the likelihood of failures that might cause harm and take appropriate remedial actions. Buyer will fully indemnify TI and its representatives against any damages arising out of the use of any TI components in safety-critical applications.

In some cases, TI components may be promoted specifically to facilitate safety-related applications. With such components, TI's goal is to help enable customers to design and create their own end-product solutions that meet applicable functional safety standards and requirements. Nonetheless, such components are subject to these terms.

No TI components are authorized for use in FDA Class III (or similar life-critical medical equipment) unless authorized officers of the parties have executed a special agreement specifically governing such use.

Only those TI components which TI has specifically designated as military grade or "enhanced plastic" are designed and intended for use in military/aerospace applications or environments. Buyer acknowledges and agrees that any military or aerospace use of TI components which have **not** been so designated is solely at the Buyer's risk, and that Buyer is solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI has specifically designated certain components as meeting ISO/TS16949 requirements, mainly for automotive use. In any case of use of non-designated products, TI will not be responsible for any failure to meet ISO/TS16949.

Products

Audio	www.ti.com/audio
Amplifiers	amplifier.ti.com
Data Converters	dataconverter.ti.com
DLP® Products	www.dlp.com
DSP	dsp.ti.com
Clocks and Timers	www.ti.com/clocks
Interface	interface.ti.com
Logic	logic.ti.com
Power Mgmt	power.ti.com
Microcontrollers	microcontroller.ti.com
RFID	www.ti-rfid.com
OMAP Applications Processors	www.ti.com/omap
Wireless Connectivity	www.ti.com/wirelessconnectivity

Applications

Automotive and Transportation	www.ti.com/automotive
Communications and Telecom	www.ti.com/communications
Computers and Peripherals	www.ti.com/computers
Consumer Electronics	www.ti.com/consumer-apps
Energy and Lighting	www.ti.com/energy
Industrial	www.ti.com/industrial
Medical	www.ti.com/medical
Security	www.ti.com/security
Space, Avionics and Defense	www.ti.com/space-avionics-defense
Video and Imaging	www.ti.com/video

TI E2E Community

e2e.ti.com

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

[Texas Instruments:](#)

[DS26C31TM](#) [DS26C31TM/NOPB](#) [DS26C31TMX](#) [DS26C31TMX/NOPB](#) [DS26C31TN](#) [DS26C31TN/NOPB](#)